



JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD
TO-252-2LK Plastic-Encapsulate Thyristors

CT308D 3Q TRIACs

MAIN CHARACTERISTICS

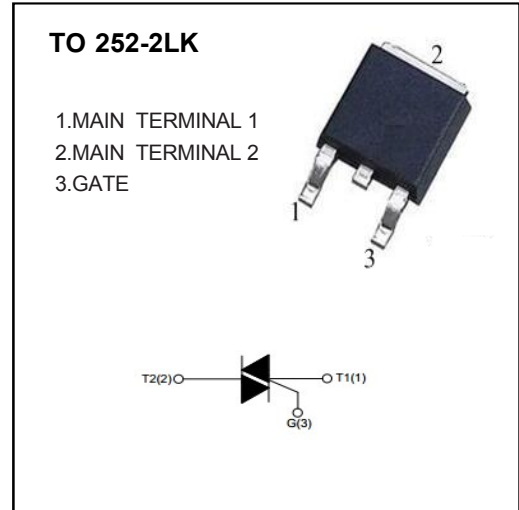
$I_{T(RMS)}$		8A
V_{DRM}/V_{RRM}	CT308D-600S/C	600V
	CT308D-800S/C	800V
V_{TM}		1.55V

FEATURES

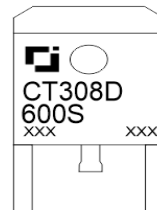
- NPNPN 5-layer Structure TRIACs
- Mesa Glass Passivated Technology
- Multi Layers Metal Electrodes
- High Junction Temperature
- Good Commutation Performance
- High dV/dt and dI/dt

APPLICATIONS

- Heater Control
- Motor Speed Controller
- Mixer



MARKING



CT308D:Series Code
 600S:Depends on VDRM
 and IGT
 XXX:Internal Code

ABSOLUTE RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test condition	Value	Unit	
V_{DRM}/V_{RRM}	Repetitive peak off-state voltage	$T_j=25^\circ\text{C}$	CT308D-600S/C	600	V
			CT308D-800S/C	800	V
$I_{T(RMS)}$	RMS on-state current	TO-252-2LK($T_C \leq 110^\circ\text{C}$), Fig. 1,2	8	A	
I_{TSM}	Non repetitive surge peak on-state current	Full sine wave , $T_j(\text{init})=25^\circ\text{C}$, $t_p=20\text{ms}$; Fig. 3,5	80	A	
I^2t	I^2t value	$t_p=10\text{ms}$	36	A^2s	
di_T/dt	Critical rate of rise of on-state current	$I_G=2 \cdot I_{GT}$, $t_r \leq 10\text{ns}$, $F=120\text{Hz}$, $T_j=125^\circ\text{C}$	I - II - III	50	$\text{A}/\mu\text{s}$
			IV	n/a	
I_{GM}	Peak gate current	$t_p=20\mu\text{s}$, $T_j=125^\circ\text{C}$	2	A	
$P_{G(AV)}$	Average gate power	$T_j=125^\circ\text{C}$	0.5	W	
T_{STG}	Storage temperature		-40~+150	$^\circ\text{C}$	
T_j	Operating junction temperature		-40~+125		

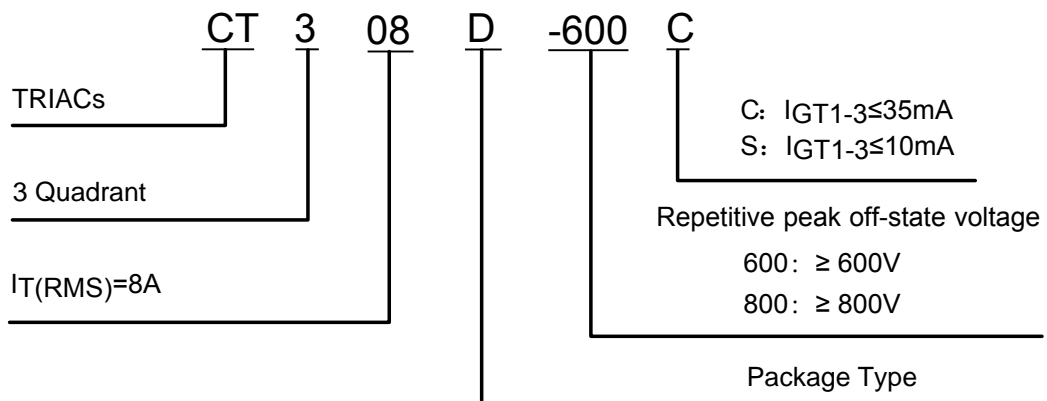
ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Symbol	Parameter	Test condition	Value		Unit	
			S	C		
I _{GT}	Gate trigger current	V _D =12V, I _T =0.1A, T _j =25°C, Fig. 6	I - II - III	≤10	≤35	mA
			IV	n/a	n/a	
V _{GT}	Gate trigger voltage	T _j =25°C, Fig. 6	I - II - III	≤1.3		V
V _{GD}	Non-triggering gate voltage	V _D =V _{DRM} , T _j =125°C		≥0.2		V
I _H	Holding current	V _D =12V, I _{GT} =0.1A, T _j =25°C, Fig. 6	I - II - III	≤15	≤25	mA
I _L	Latching current		I - III	≤20	≤30	mA
			II	≤25	≤35	mA
dV _D /dt	Critical rate of rise of off-state	V _D =67%V _{DRM} , Gate Open T _j =125°C		≥40	≥80	V/μs
V _{TM}	On-state Voltage	I _{TM} =10A, t _p =380μs, s, Fig. 4		≤1.55		V
I _{DRM} / I _{RPM}	Repetitive peak off-state current	V _D =V _{DRM} /V _{RPM} , T _j =25°C		≤5	≤5	μA
		V _D =V _{DRM} /V _{RPM} , T _j =125°C		≤1	≤1	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th} (j-c)	Junction to case (AC)	TO-252-2LK	1.6 °C/W
R _{th} (j-a)	Junction to ambient	TO-252-2LK	70 °C/W

PART NUMBER



CHARACTERISTICS CURVES

FIG.1: Maximum power dissipation versus RMS on-state current (full cycle)

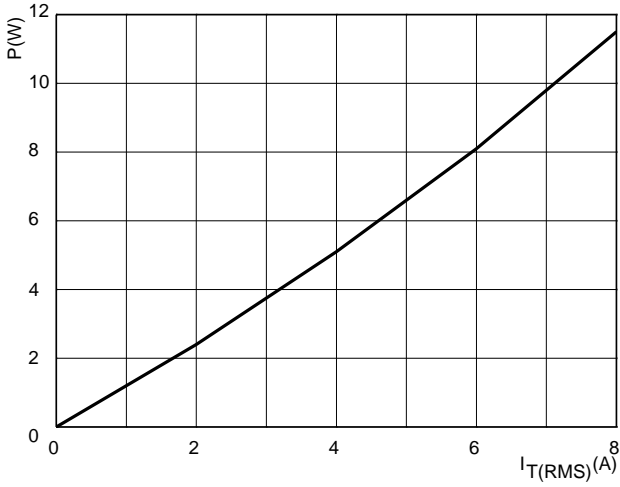


FIG.2: RMS on-state current versus case temperature (full cycle)

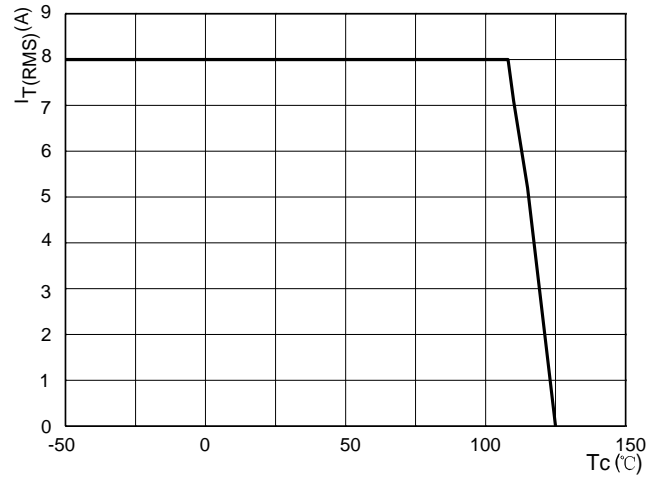


FIG.3: Surge peak on-state current versus number of cycles

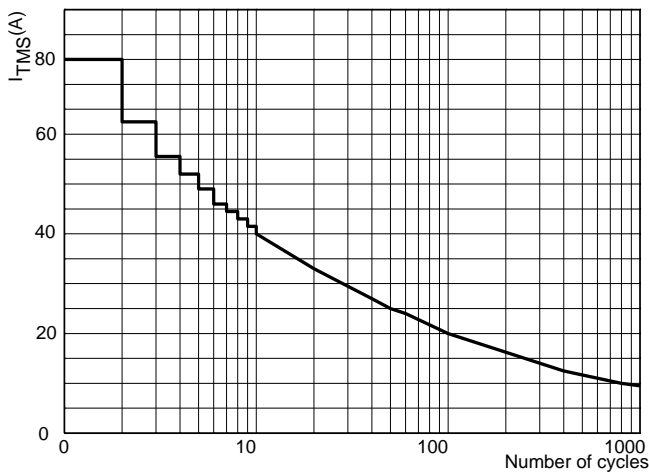


FIG.4: On-state characteristics (maximum values)

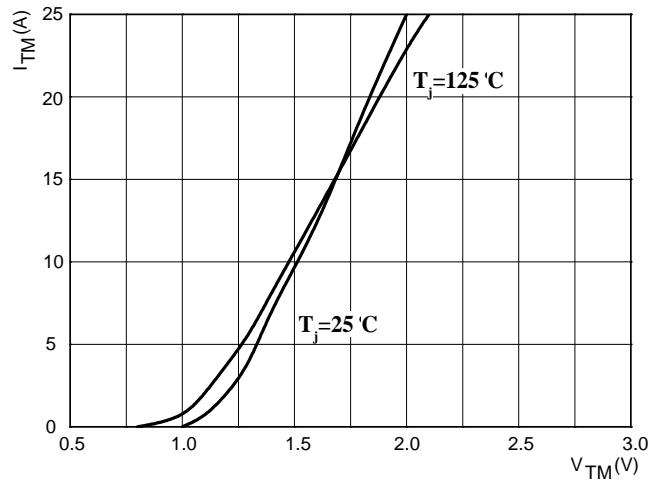


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$

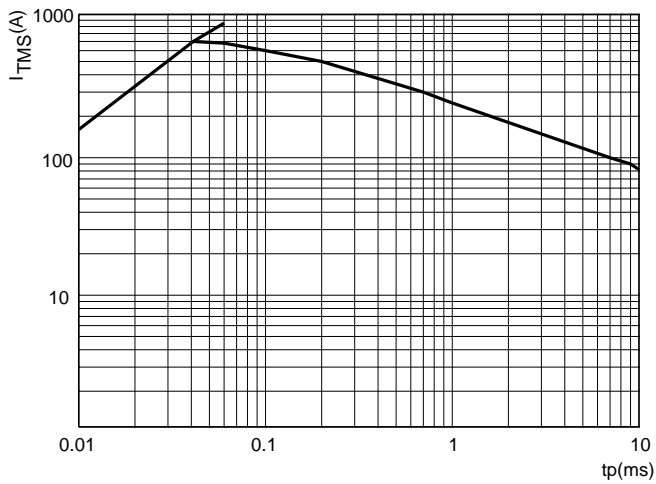
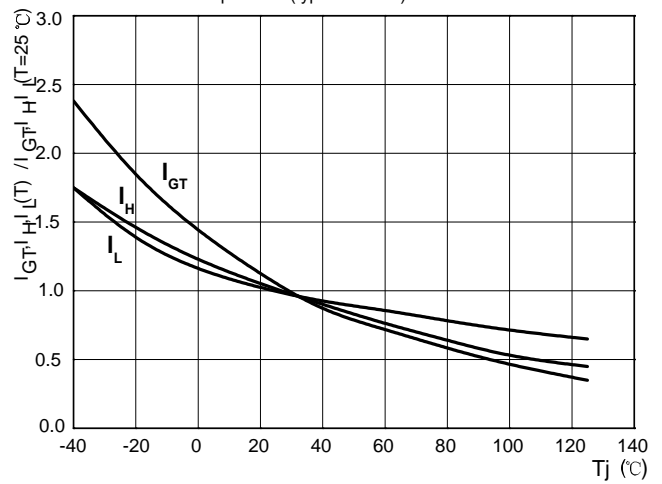
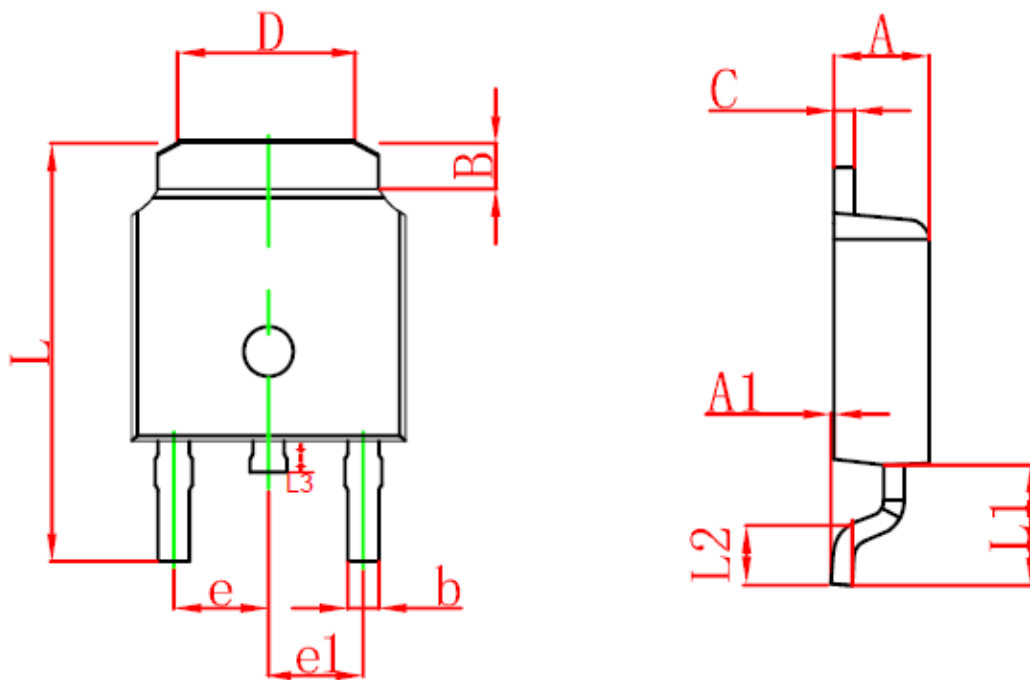


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature (typical values)



TO-252-2LK PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	2.100	2.500
A1	0.000	0.127
B	1.070	1.470
b	0.710	0.810
C	0.700	0.900
D	3.400	3.800
e	2.250	2.350
e1	2.250	2.350
L	10.000	10.400
L1	2.600	3.000
L2	1.400	1.700
L3	0.600	1.000

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